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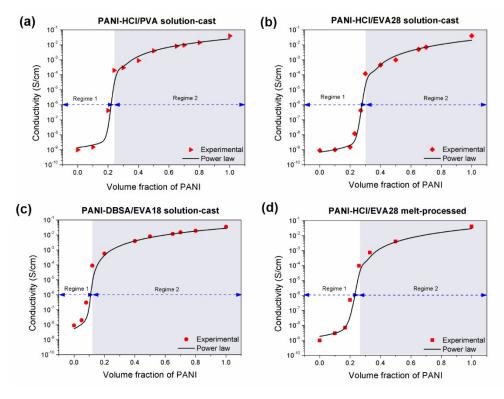
## Supplementary information

## Strain induced insulator-to-semiconductor transition in conducting polymer composites originating from the auxetic behaviour of hierarchical structures

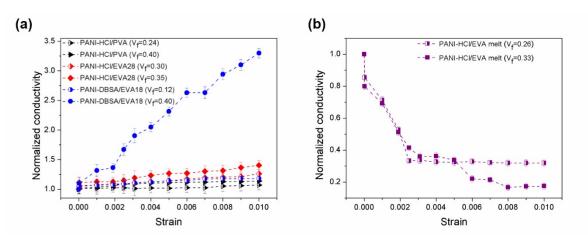
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Power law at three different regimes corresponding to above, below and at percolation are:

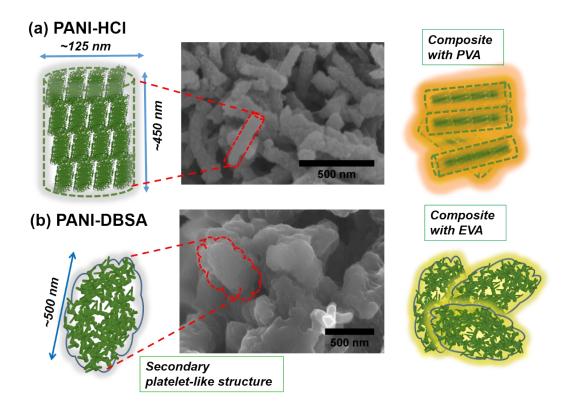
- a) When the volume fraction  $V_f$  of PANI in the blend just exceeds the percolation threshold  $V_{fc}$ , the conductivity of the composite can be predicted by,  $\sigma_c \propto \sigma_1 * (V_f V_{fc})^t$ , where,  $\sigma_1$  is the conductivity of pure PANI and t is the exponent in Power law.
- b) When  $V_f < V_{fc}$ , conductivity of the composite is predicted by,  $\sigma_c \propto \sigma_2 * (V_{fc} V_f)^{-v}$ , where,  $\sigma_2$  is the conductivity of the insulating polymer and v is the exponent in Power law.
- c) When  $|V_f V_{fc}| \to 0$ , at the cross-over region, the conductivity of the composite is predicted by,  $\sigma_c \propto \sigma_2^{\ u} * \sigma_1^{\ 1-u}$  where,  $u = \frac{t}{t+v}$



**Fig. S1.** Conductivity variation with increasing volume fraction of PANI in (a) PANI-HCI/PVA (b) PANI-HCI/EVA28 (c) PANI-DBSA/EVA18 (all solution cast) and (d) PANI-HCI/EVA28 (melt processed), by both experimental and power law fit. Regime 1 corresponds to insulator and Regime 2 to semiconductor.



**Fig. S2**. Conductivity variation with strain at and above percolation threshold for different PANI composites (a) solution cast showing increase and (b) melt processed showing decrease in conductivity with strain. Half-filled symbols represent composites at percolation and closed symbols represent composites above percolation. The lines are to guide the eye.



**Fig. S3.** Schematic and SEM images of (a) PANI-HCl consisting of tertiary rod-shaped agglomerates of ~450 nm length and 125 nm dia formed from secondary agglomerates of ~100 nm size, which are formed by the aggregation of 10 nm primary nano-rods. (b) PANI-DBSA consisting of agglomerated circular platelet-like structures of length ~500 nm and thickness ~10 nm formed by the aggregation of primary nano-rods.

**Table S1.** Experimentally obtained percolation threshold, power law exponents and conductivity for different PANI composites

Composite	Percolation threshold	Power law exponents		Conductivity at $V_{fc}$ (S/cm)
	$V_{fc}$	T	ν	-
PANI-HCI/PVA	0.24	1.70	0.72	2.0 x 10 <sup>-4</sup>
PANI-HCI/EVA28	0.30	1.90	0.95	1.2 x 10 <sup>-4</sup>
PANI-DBSA/EVA18	0.12	1.70	0.90	0.90x10 <sup>-4</sup>
PANI-HCI/EVA28 (melt processed)	0.26	1.80	0.98	0.90x10 <sup>-4</sup>

**Table S2.**Poisson's ratio of PANI composites with 1% strain

Sample	Blend ratio	Poisson's ratio	
	(PANI/	$artheta_{\chi\gamma}$	
	insulating	·	
	matrix)		
PANI-HCI/PVA	0/100	0.42-0.48	
	20/80	0.32	
	24/76	0.3	
	40/60	0.1	
PANI-HCI/EVA28	0/100	0.2-0.35	
	28/72	0.187	
	30/70	0.18	
	35/65	0.1	
PANI-DBSA/EVA18	0/100	0.2-0.35	
	8/92	0.16	
	12/88	0.15	
	40/60	0.1	
PANI-HCI/EVA28 melt processed	0/100	0.37	
•	26/74	0.15	
	33/67	0.12	